Power MOSFET

40 V, 5.8 A, Dual N-Channel SOIC-8 Features

- Designed for use in low voltage, high speed switching applications
- Ultra Low On-Resistance Provides
 - Higher Efficiency and Extends Battery Life
 - $-R_{DS(on)} = 0.027 \Omega$, $V_{GS} = 10 V$ (Typ)
 - $-R_{DS(on)} = 0.034 \Omega$, $V_{GS} = 4.5 V (Typ)$
- Miniature SOIC-8 Surface Mount Package Saves Board Space
- Diode is Characterized for Use in Bridge Circuits
- Diode Exhibits High Speed, with Soft Recovery
- NVMD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable*
- These Devices are Pb-Free and are RoHS Compliant

Applications

- DC–DC Converters
- Computers
- Printers
- Cellular and Cordless Phones
- Disk Drives and Tape Drives

MAXIMUM RATINGS (T_{.1} = 25°C unless otherwise noted)

	Rating Symbol Value Unit						
Symbol	Value	Unit					
V _{DSS}	40	V					
V _{GS}	±20	V					
I _D I _{DM}	5.8 29	Adc Apk					
I _D	4.6	Adc					
PD	2.0 1.29	W					
T _J , T _{stg}	–55 to +150	°C					
E _{AS}	245	mJ					
R _{θJA}	62.5 97	°C/W					
TL	260	°C					
	V _{DSS} V _{GS} I _D I _D I _D P _D T _J , T _{stg} E _{AS} R _{θJA}	$\begin{tabular}{ c c c c c } \hline V_{DSS} & 40 \\ \hline V_{GS} & \pm 20 \\ \hline I_D & 5.8 \\ 29 \\ \hline I_D & 2.0 \\ 1.29 \\ \hline T_J, T_{stg} & -55 \text{ to } +150 \\ \hline E_{AS} & 245 \\ \hline R_{\theta JA} & 62.5 \\ 97 \\ \hline \end{tabular}$					

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. When surface mounted to an FR4 board using 1" pad size, t \leq 10 s 2. When surface mounted to an FR4 board using 1" pad size, t = steady state

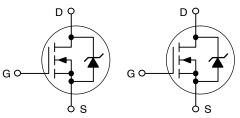


ON Semiconductor®

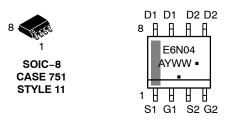
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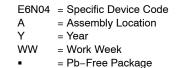
V _{DSS}	R _{DS(ON)} Typ	I _D Max
40 V	27 mΩ @ V _{GS} = 10 V	5.8 A

N-Channel



MARKING DIAGRAM & PIN ASSIGNMENT





(Note: Microdot may be in either location)

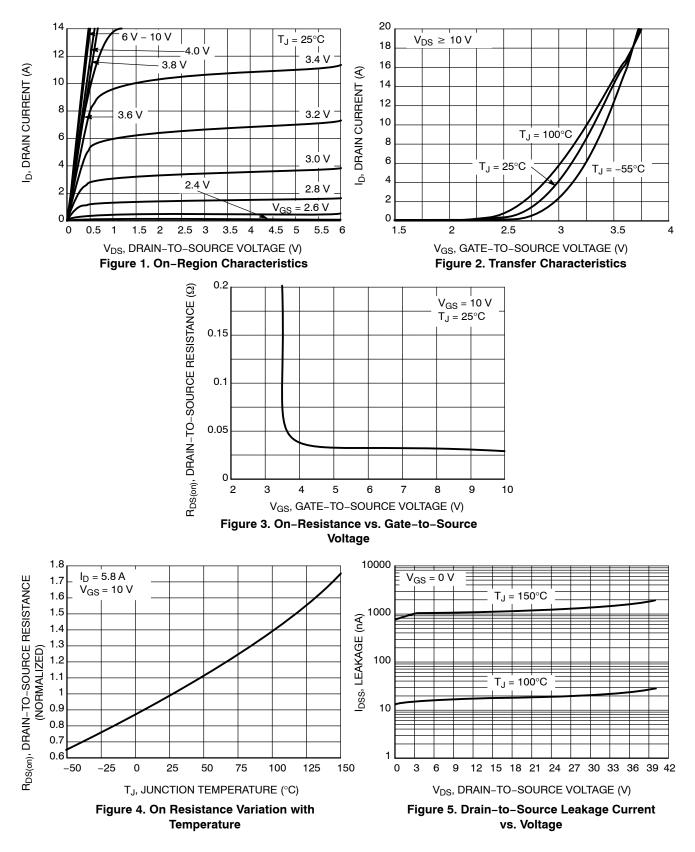
ORDERING INFORMATION

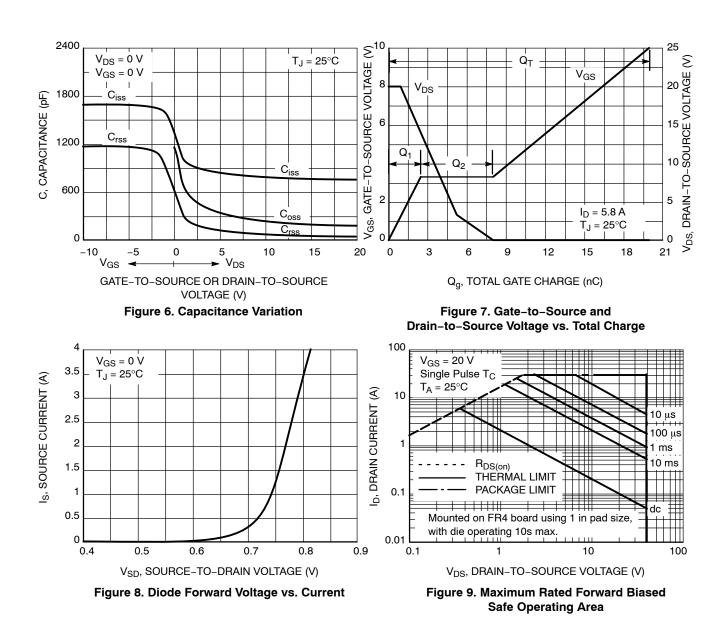
Device	Package	Shipping [†]
NTMD6N04R2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NVMD6N04R2G*	SOIC-8 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Cha	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltag (V _{GS} = 0 Vdc, I _D = 250 μA) Temperature Coefficient (Positive)	V _{(BR)DSS} V _{(BR)DSS} /T _J	40	47 45		Vdc mV/°C	
Zero Gate Voltage Drain Current $(V_{DS} = 40 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 25^{\circ}\text{C})$ $(V_{DS} = 40 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C})$			-		1.0 10	μAdc
$ \begin{array}{c} \mbox{Gate-Body Leakage Current} \\ \mbox{(V}_{GS} = \pm 20 \mbox{ Vdc}, \mbox{V}_{DS} = 0 \mbox{ Vdc}) \end{array} $			-	_	±100	nAdd
ON CHARACTERISTICS (Note 3)				1	1	
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$ Temperature Coefficient (Negative)			1.0	1.9 4.7	3.0 _	Vdc mV/°C
Static Drain-to-Source On-State Resistance ($V_{GS} = 10 \text{ Vdc}, I_D = 5.8 \text{ Adc}$) ($V_{GS} = 4.5 \text{ Vdc}, I_D = 3.9 \text{ Adc}$)		R _{DS(on)}	-	0.027 0.034	0.034 0.043	Ω
Forward Transconductance $(V_{DS} = 10 \text{ Vdc}, I_D = 5.8 \text{ Adc})$	9fs	-	8.12	-	Mhos	
OYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	723	900	pF
Output Capacitance	(V _{DS} = 32 Vdc, V _{GS} = 0 Vdc, f = 1.0 MHz)	C _{oss}	-	156	225	
Reverse Transfer Capacitance		C _{rss}	-	53	75	
	Notes 3 & 4)					•
Turn-On Delay Time		t _{d(on)}	-	10	18	ns
Rise Time	$(V_{DD} = 20 \text{ Vdc}, I_D = 5.8 \text{ A}, V_{GS} = 10 \text{ V},$	t _r	-	20	35	
Turn-Off Delay Time	$R_{\rm G} = 6 \Omega$	t _{d(off)}	-	45	70	
Fall Time		t _f	-	40	65	
Turn-On Delay Time		t _{d(on)}	-	15	-	ns
Rise Time	$(V_{DD} = 20 \text{ Vdc}, I_D = 5.8 \text{ A},$	t _r	-	55	-	
Turn-Off Delay Time		t _{d(off)}	-	30	-	
Fall Time		t _f	-	35	-	
Gate Charge		Q _T	-	20	30	nC
	(V _{DS} = 20 Vdc, V _{GS} = 10 Vdc,	Q _{gs}	-	2.5	-	-
	I _D = 5.8 A)	Q _{gd}	-	5.5	-	
BODY-DRAIN DIODE RATINGS (No	te 3)			•	•	-
Diode Forward On-Voltage		V _{SD}	-	0.76 0.56	1.1 -	Vdc
Reverse Recovery Time		t _{rr}	_	23	-	ns
	(I _S = 1.7 A, V _{GS} = 0 V, dI _S /dt = 100 A/us)	t _a	-	16	-]
		t _b	-	7	-	1
Reverse Recovery Stored Charge ($I_S = 1.7 \text{ A}$, $dI_S/dt = 100 \text{ A}/\mu\text{s}$, $V_{GS} =$	0 V)	Q _{RR}	-	20	-	nC

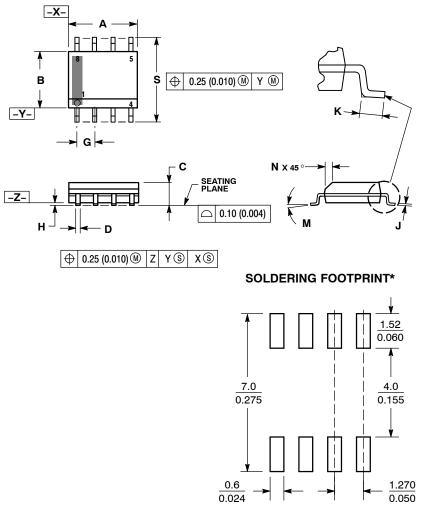




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PACKAGE DIMENSIONS

SOIC-8 NB CASE 751-07 **ISSUE AK**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER. З.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 (0.006) 4
- PER SIDE 5.
- PER SIDE. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT
- MAXIMUM MATERIAL CONDITION. 751–01 THRU 751–06 ARE OBSOLETE. NEW 6. STANDARD IS 751-07.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
в	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27 BSC		0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
К	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
Ν	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

STYLE 11: 1. SOURCE 1 GATE 1 З. SOURCE 2 GATE 2 4

- DRAIN 2 5 DRAIN 2 6.
- 7 DRAIN 1
- DRAIN 1 8.

mm

(inches

SCALE 6:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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